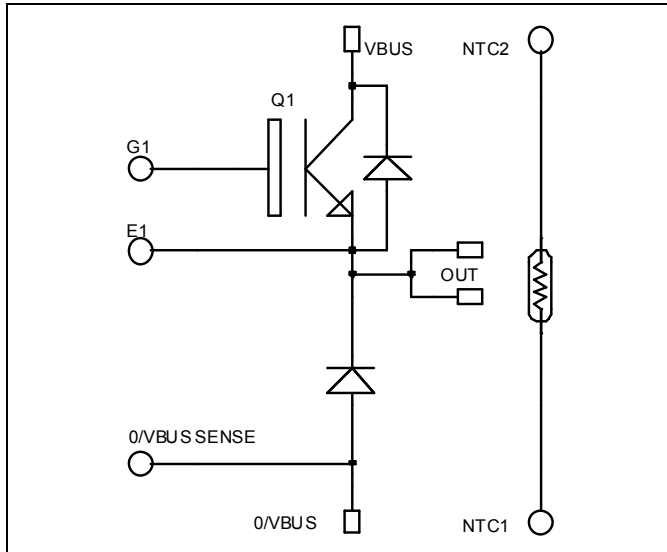


***Buck chopper
NPT IGBT Power Module***

**$V_{CES} = 600V$
 $I_C = 180A @ T_c = 80^\circ C$**



Application

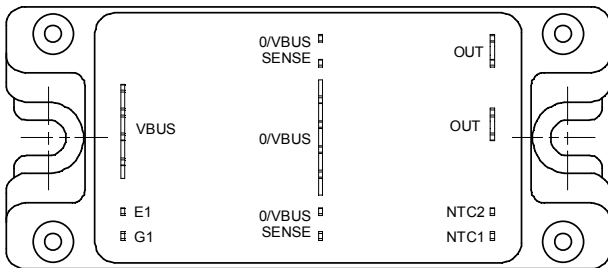
- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) THUNDERBOLT IGBT®
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - Avalanche energy rated
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Easy paralleling due to positive TC of VCEsat
- Low profile



Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	600	V
I_C	Continuous Collector Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
I_{CM}	Pulsed Collector Current	$T_c = 25^\circ C$	630
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	833
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^\circ C$	630A @ 600V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
BV_{CES}	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 150\mu A$	600			V
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$ $V_{CE} = 600V$			150 3000	μA
$V_{CE(on)}$	Collector Emitter on Voltage	$V_{GE} = 15V$ $I_C = 180A$		2.0 2.2	2.5	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 2mA$	3		5	V
I_{GES}	Gate - Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			± 200	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
C_{ies}	Input Capacitance	$V_{GE} = 0V$		8.6		nF	
C_{oes}	Output Capacitance	$V_{CE} = 25V$		0.94			
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		0.8			
Q_g	Total gate Charge	$V_{GS} = 15V$		660		nC	
Q_{gc}	Gate - Emitter Charge	$V_{Bus} = 300V$		580			
Q_{gc}	Gate - Collector Charge	$I_C = 180A$		400			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 180A$ $R_G = 2.5\Omega$		26		ns	
T_r	Rise Time			25			
$T_{d(off)}$	Turn-off Delay Time			150			
T_f	Fall Time			30			
E_{on}	Turn-on Switching Energy ①			6.74			mJ
E_{off}	Turn-off Switching Energy ②			5.74			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 180A$ $R_G = 2.5\Omega$		26		ns	
T_r	Rise Time			25			
$T_{d(off)}$	Turn-off Delay Time			170			
T_f	Fall Time			40			
E_{on}	Turn-on Switching Energy ①			8.6			mJ
E_{off}	Turn-off Switching Energy ②			7			

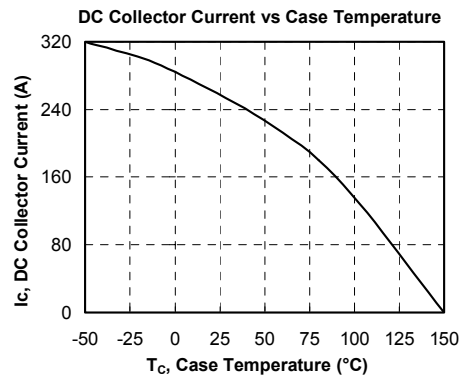
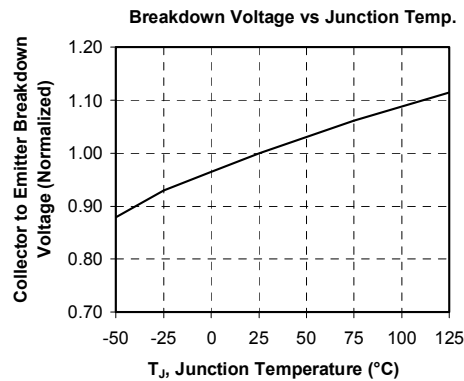
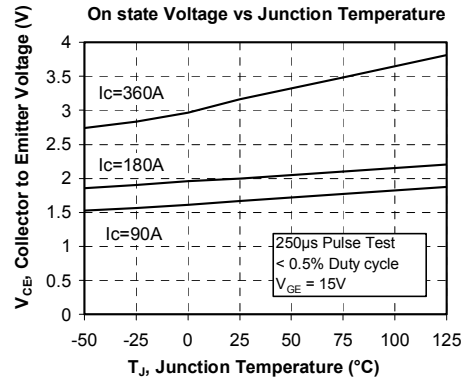
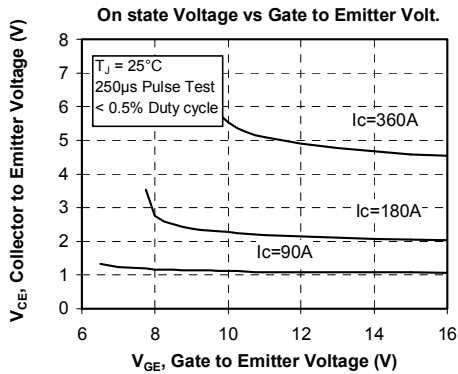
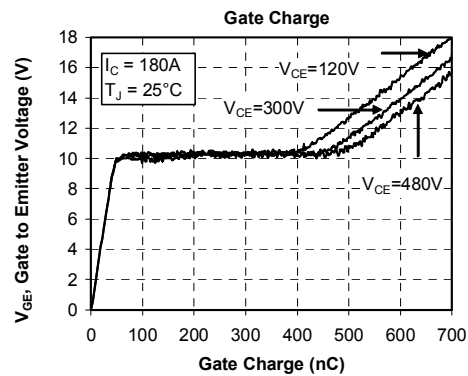
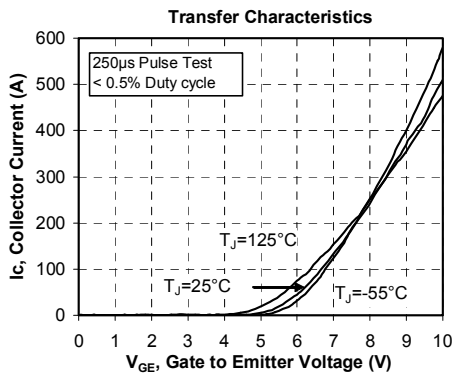
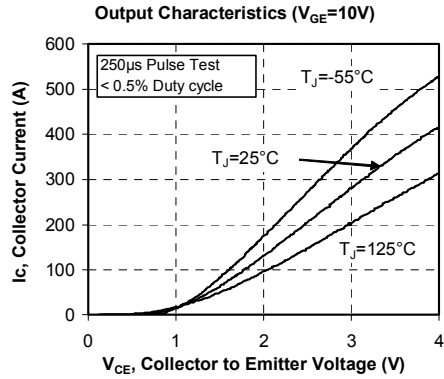
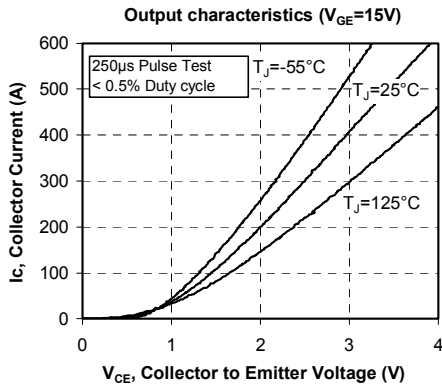
Reverse diode ratings and characteristics

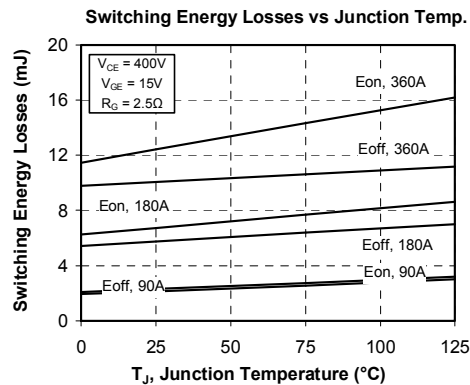
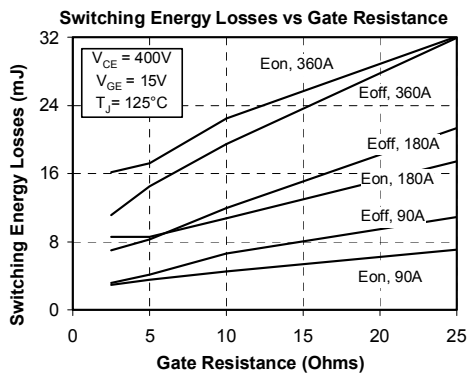
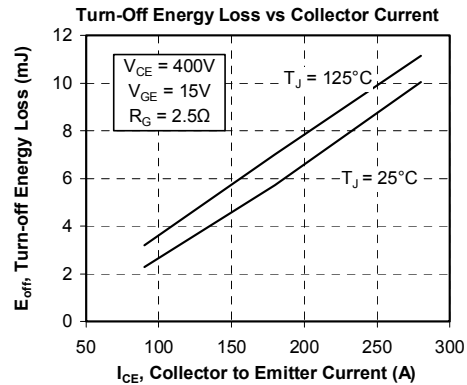
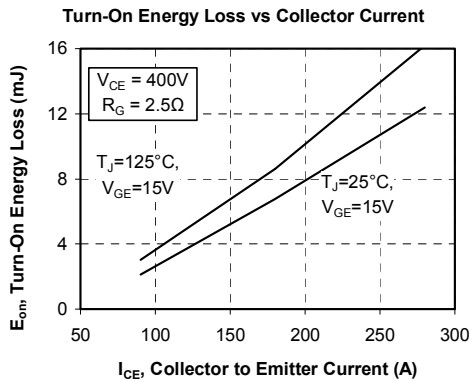
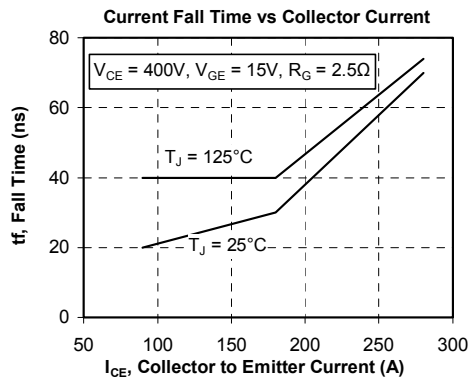
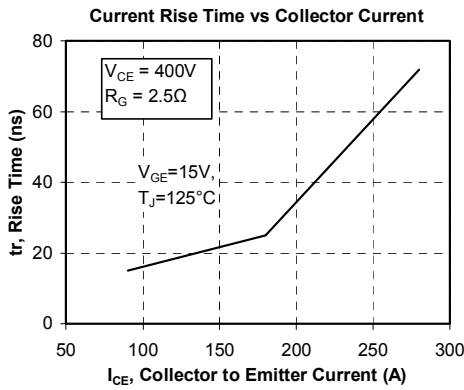
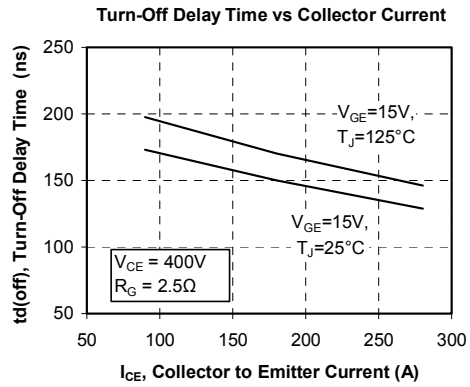
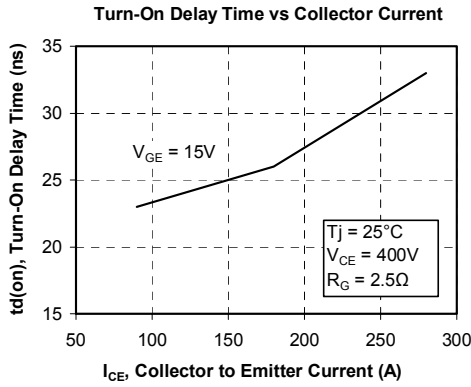
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{F(AV)}$	Maximum Average Forward Current	50% duty cycle $T_c = 80^\circ\text{C}$		200		A
V_F	Diode Forward Voltage	$I_F = 200A$		1.6	1.8	V
		$I_F = 400A$		1.9		
		$I_F = 200A$ $T_j = 125^\circ\text{C}$		1.4		
t_{rr}	Reverse Recovery Time	$I_F = 200A$ $V_R = 400V$ $di/dt = 400A/\mu s$	$T_j = 25^\circ\text{C}$	180		ns
			$T_j = 125^\circ\text{C}$	220		
Q_{rr}	Reverse Recovery Charge	$I_F = 200A$ $V_R = 400V$ $di/dt = 400A/\mu s$	$T_j = 25^\circ\text{C}$	780		nC
			$T_j = 125^\circ\text{C}$	2900		

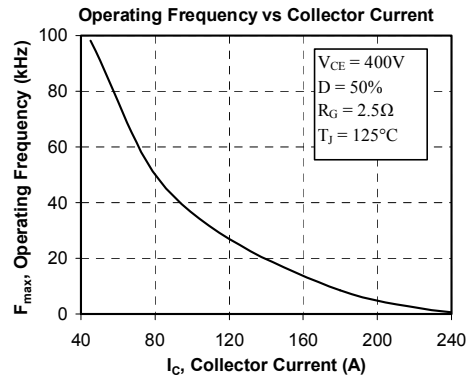
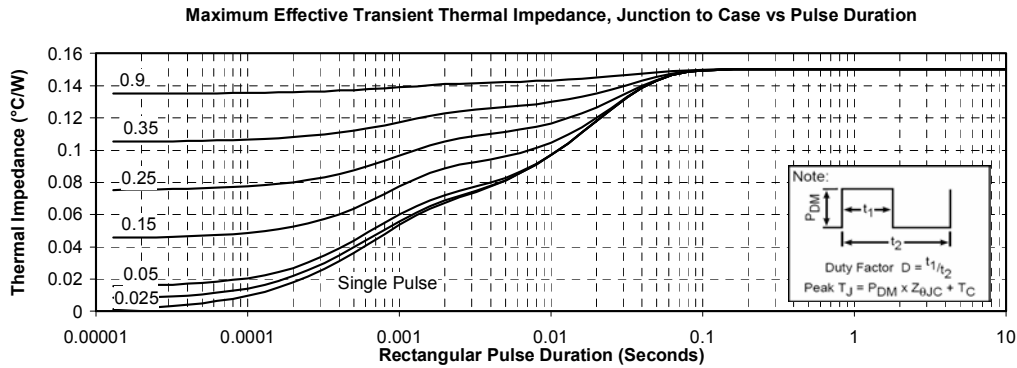
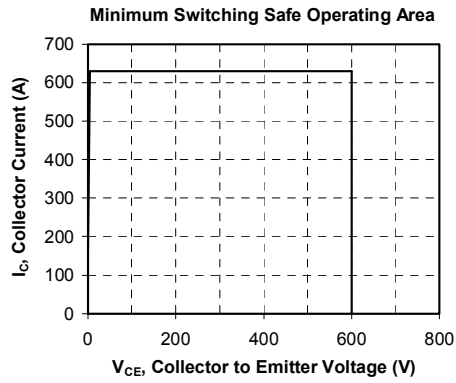
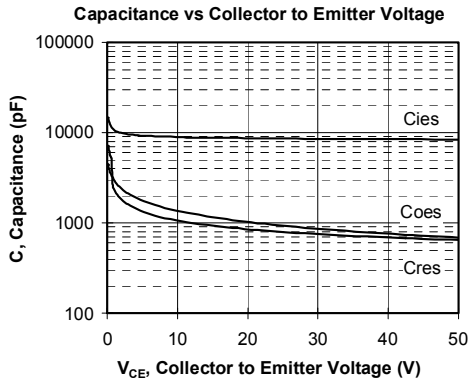
① E_{on} includes diode reverse recovery

② In accordance with JEDEC standard JESD24-1

Typical Performance Curve







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